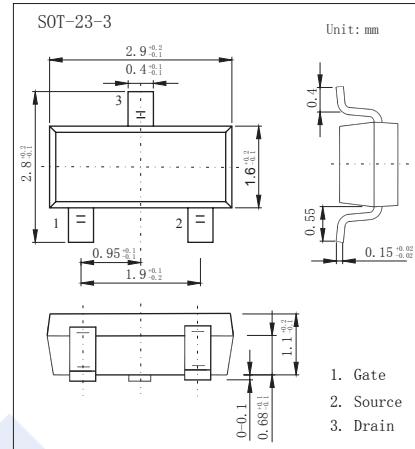
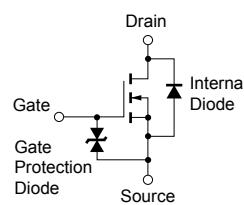


N-Channel MOSFET

2SK1399

■ Features

- Can be driven by a 3.0-V power source
- Not necessary to consider driving current because of it is high input impedance
- Possible to reduce the number of parts by omitting the bias resistor
- Complements the 2SJ185



■ Absolute Maximum Ratings Ta = 25°C

| Parameter | Symbol | Rating | Unit |
|-------------------------------|------------------|------------|------|
| Drain-Source Voltage | V _{DS} | 50 | V |
| Gate-Source Voltage | V _{GGS} | ±7 | |
| Continuous Drain Current | I _D | 100 | mA |
| Pulsed Drain Current (Note.1) | I _{DM} | 200 | |
| Power Dissipation Ta = 25°C | P _D | 200 | mW |
| Junction Temperature | T _J | 150 | °C |
| Operating Temperature | T _{opt} | -55 to 80 | |
| Storage Temperature Range | T _{stg} | -55 to 150 | |

Note.1: PW ≤ 10ms, Duty Cycle ≤ 50%

■ Electrical Characteristics Ta = 25°C

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|-----------------------------------|-----------------------|--|-----|-----|-----|------|
| Drain-Source Breakdown Voltage | V _{DSS} | I _D =250 μA, V _{GGS} =0V | 50 | | | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =50V, V _{GGS} =0V | | | 10 | uA |
| Gate-Body Leakage Current | I _{GSS} | V _{DS} =0V, V _{GGS} =±7V | | | ±5 | uA |
| Gate Cut-off Voltage | V _{GGS(off)} | V _{DS} =3V I _D =1uA | 0.9 | | 1.5 | V |
| Static Drain-Source On-Resistance | R _{D(on)} | V _{GGS} =2.5V, I _D =10m A | | | 40 | Ω |
| | | V _{GGS} =4V, I _D =10m A | | | 20 | |
| Forward Transconductance | g _F | V _{DS} =3V, I _D =10m A | 20 | 38 | | ms |
| Input Capacitance | C _{iss} | V _{GGS} =0V, V _{DS} =3V, f=1MHz | | 8 | | pF |
| Output Capacitance | C _{oss} | | | 7 | | |
| Reverse Transfer Capacitance | C _{rss} | | | 3 | | |
| Turn-On Delay Time | t _{d(on)} | V _{GGS} =3V, V _{DS} =3V, I _D =20mA, R _L =150 Ω, R _G =10 Ω | | 15 | | ns |
| Turn-On Rise Time | t _r | | | 100 | | |
| Turn-Off Delay Time | t _{d(off)} | | | 30 | | |
| Turn-Off Fall Time | t _f | | | 35 | | |

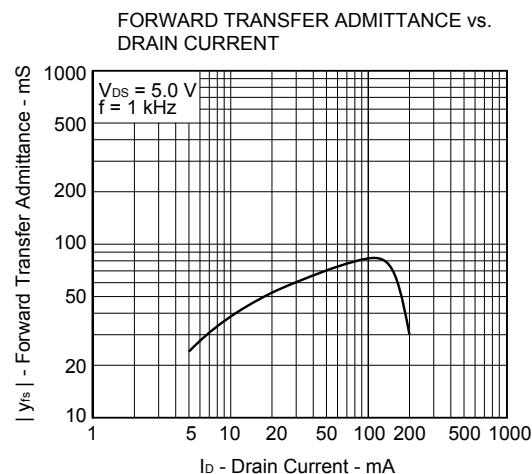
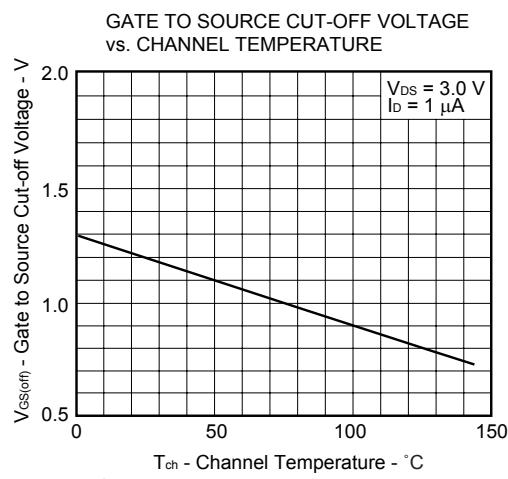
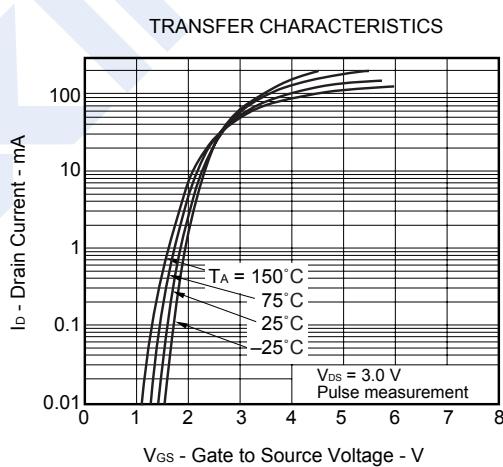
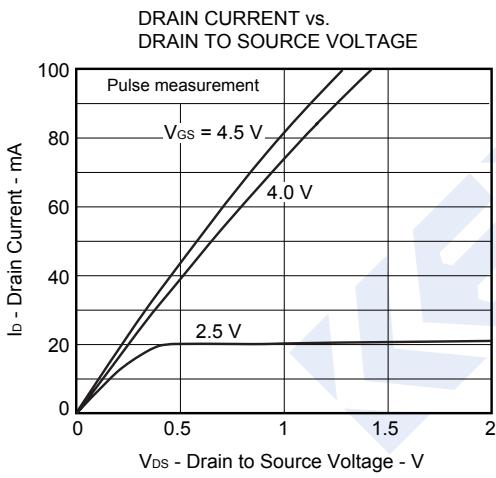
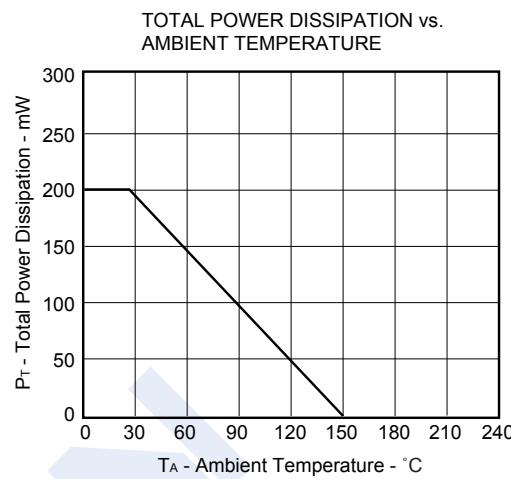
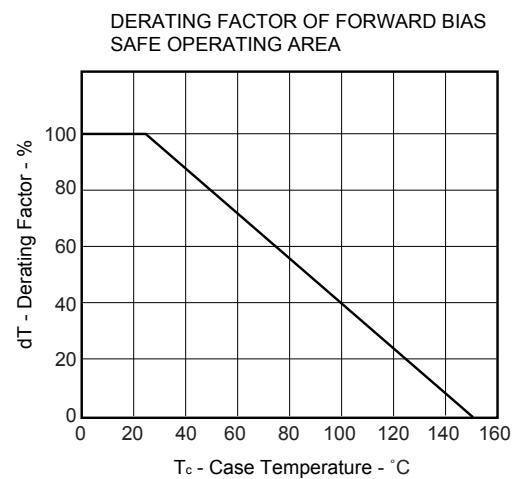
■ Marking

| | |
|---------|-----|
| Marking | G12 |
|---------|-----|

N-Channel MOSFET

2SK1399

■ Typical Characteristics



N-Channel MOSFET

2SK1399

■ Typical Characteristics

